









SN54LVC86A, SN74LVC86A

SCAS288R - JANUARY 1993 - REVISED AUGUST 2024

SNx4LVC86A Quadruple 2-Input Exclusive-OR Gates

1 Features

- Operate from 1.65V to 3.6V
- Specified from -40°C to 85°C, -40°C to 125°C, and -55°C to 125°C
- Inputs accept voltages to 5.5V
- Max t_{pd} of 4.6ns at 3.3V
- Typical V_{OLP} (output ground bounce) < 0.8 V at $V_{CC} = 3.3 V$, $T_A = 25 ^{\circ} C$
- Typical V_{OHV} (output V_{OH} undershoot) >2V at V_{CC} = 3.3V, T_A = 25°C
- Latch-up performance exceeds 250 mA per JESD
- ESD protection exceeds JESD 22
 - 2000V human-body model (A114-A)
 - 1000V charged-device model (C101)

2 Applications

- AV receiver
- Audio dock: portable
- Blu-ray player and home theater
- MP3 player or recorder
- Personal digital assistant (PDA)
- Power: telecom/server AC/DC supply: single controller: analog and digital
- Solid state drive (SSD): client and enterprise
- TV: LCD, digital, and high-definition (HDTV)
- Tablet: enterprise
- Video analytics: server
- Wireless headset, keyboard, and mouse

3 Description

The SN54LVC86A quadruple 2-input exclusive-OR gate is designed for 2.7V to 3.6V V_{CC} operation, and the SN74LVC86A quadruple 2-input exclusive-OR gate is designed for 1.65V to 3.6V V_{CC} operation.

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾	BODY SIZE ⁽³⁾		
	BQA (WQFN, 14)	3mm × 2.5mm	3mm × 2.5mm		
	RGY (VQFN, 14)	3.50mm × 3.50mm	3.50mm × 3.50mm		
	D (SOIC, 14)	8.65mm x 6mm	8.65mm × 3.91mm		
SNx4LVC86A	NS (SOP, 14)	10.2mm x 7.8mm	10.20mm × 5.30mm		
SINX4LVC60A	DB (SSOP, 14)	6.2mm x 7.8mm	6.20mm × 5.30mm		
	PW (TSSOP, 14)	5mm x 6.4mm	5.00mm × 4.40mm		
	W (CFP, 14)	9.21mm × 9mm	9.21mm × 6.29mm		
	FK (LCCC, 20)	8.89mm × 8.89mm	8.89mm × 8.89mm		

- For more information, see Mechanical, Packaging, and Orderable Information.
- The package size (length × width) is a nominal value and includes pins, where applicable.
- The body size (length × width) is a nominal value and does not include pins.



Exclusive-OR Logic



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4 Pin Configuration and Functions

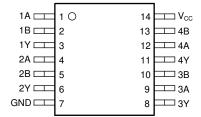


Figure 4-1. SN54LVC86A J or W Package, 14-Pin CDIP or CFP; SN74LVC86A D, DB, NS, or PW Package, 14-Pin SOIC, SSOP, SOP or TSSOP (Top View)

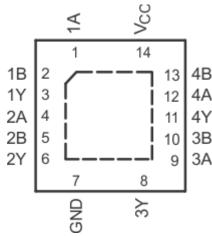


Figure 4-2. SN74LVC86A BQA or RGY Package, 14-Pin WQFN or VQFN (Top View)

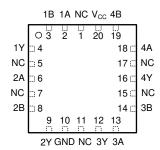


Figure 4-3. SN54LVC86A FK Package, 14-Pin LCCC (Top View)

Table 4-1. Pin Functions

	PIN					
NO.	J, W, D, DB, NS, PW, RGY	FK	1/0	DESCRIPTION		
	14 PINS	20 PINS				
1A	1	2	I	Gate 1 input		
1B	2	3	I	Gate 1 input		
1Y	3	4	0	Gate 1 output		
2A	4	6	I	Gate 2 input		
2B	5	8	I	Gate 2 input		
2Y	6	9	0	Gate 2 output		
3Y	8	12	0	Gate 3 output		
3A	9	13	I	Gate 3 input		
3B	10	14	I	Gate 3 input		
4Y	11	16	0	Gate 4 output		
4A	12	18	I	Gate 4 input		
4B	13	19	I	Gate 4 input		
GND	7	10	_	Ground Pin		
NC	_	1, 5, 7, 11, 15, 17	_	Do not connect		
V _{CC}	14	20	_	Power Pin		



5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	6.5	V
VI	Input voltage range ⁽¹⁾		-0.5	6.5	V
Vo	Output voltage range ^{(1) (2)}		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current			±50	mA
	Continuous current through V _{CC} or GND			±100	mA
P _{tot}	Power dissipation	$T_A = -40^{\circ}C \text{ to } 125^{\circ}C^{(3)}$ (4)		500	mW
T _{stg}	Storage temperature range		-65	150	°C

- (1) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.
- (2) The value of V_{CC} is provided in the recommended operating conditions table.
- (3) For the D package: above 70°C, the value of Ptot derates linearly with 8 mW/K.
- (4) For the DB, DGV, NS, and PW packages: above 60°C, the value of Ptot derates linearly with 5.5 mW/K.

5.2 ESD Ratings

			VALUE	UNIT
V	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	±2000	\/
V _(ESD)	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	±1000	V

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions, SN54LVC86A

over operating free-air temperature range (unless otherwise noted)

			SN54LV	C86A	
			-55 TO	125°C	UNIT
			MIN	MAX	
\/	Supply voltage	Operating	2	3.6	V
V _{CC}	Supply voltage	Data retention only	1.5		•
V _{IH}	High-level input voltage	V _{CC} = 2.7 V to 3.6 V	2		V
V _{IL}	Low-level input voltage	V _{CC} = 2.7 V to 3.6 V		0.8	V
VI	Input voltage		0	5.5	V
Vo	Output voltage		0	V _{CC}	V
	High-level output current	V _{CC} = 2.7 V		-12	mA
I _{OH}	nigh-level output current	V _{CC} = 3 V		-24	
	Low lovel output ourrent	V _{CC} = 2.7 V		12	mΛ
I _{OL}	Low-level output current	V _{CC} = 3 V		24	mA
Δt/Δν	Input transition rise or fall rate			9	ns/V

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5.4 Recommended Operating Conditions, SN74LVC86A

over operating free-air temperature range (unless otherwise noted)

					SN74L	VC86A				
			T _A = 25	5°C	-40 TC	85°C	-40 TO	125°C	UNIT	
			MIN	MAX	MIN	MAX	MIN	MAX		
\/	Supply voltage	Operating	1.65	3.6	1.65	3.6	1.65	3.6	V	
V _{CC}	Supply voltage	Data retention only	1.5		1.5		1.5		V	
		V _{CC} = 1.65 V to 1.95 V	0.65 × V _{CC}		0.65 × V _{CC}		0.65 × V _{CC}			
V_{IH}	High-level input voltage	V _{CC} = 2.3 V to 2.7 V	1.7		1.7		1.7		V	
	vollago	V _{CC} = 2.7 V to 3.6 V	2		2		2			
		V _{CC} = 1.65 V to 1.95 V	().35 × V _{CC}		0.35 × V _{CC}		0.35 × V _{CC}		
V _{IL}	Low-level input voltage	V _{CC} = 2.3 V to 2.7 V		0.7		0.7		0.7	V	
	vollago	V _{CC} = 2.7 V to 3.6 V		0.8		0.8		0.8		
VI	Input voltage		0	5.5	0	5.5	0	5.5	V	
Vo	Output voltage		0	V _{CC}	0	V _{CC}	0	V _{CC}	V	
		V _{CC} = 1.65 V		-4		-4		-4		
	High-level	V _{CC} = 2.3 V		-8		-8		-8	^	
I _{OH}	output current	V _{CC} = 2.7 V		-12		-12		-12	mA	
		V _{CC} = 3 V		-24		-24		-24		
		V _{CC} = 1.65 V		4		4		4		
	Low-level output	V _{CC} = 2.3 V		8		8		8	mA	
I _{OL}	current	V _{CC} = 2.7 V		12		12		12		
		V _{CC} = 3 V		24		24		24	-	
Δt/Δν	Input transition ris	se or fall rate		9		9		9	ns/V	

5.5 Thermal Information

				SN74	LVC86A			
THERMAL METRIC ⁽¹⁾		BQA	BQA D DB			NS PW		UNIT
		14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	102.3	127.8	96	123.8	150.8	92.1	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

5.6 Electrical Characteristics, SN54LVC86A

over operating free-air temperature range (unless otherwise noted)

				SN54L\		
PARAMETER	TEST CONDITIONS	V _{cc}	–55 TO	UNIT		
				MIN	TYP MAX	
	I _{OH} = -100 μA		2.7 V to 3.6 V	V _{CC} - 0.2		
V _{OH}	L = 42 mA		2.7 V	2.2		V
	I _{OH} = -12 mA	3 V	2.4		'	
	I _{OH} = -24 mA		3 V	2.2		
	I _{OL} = 100 μA		2.7 V to 3.6 V		0.2	
V_{OL}	I _{OL} = 12 mA		2.7 V		0.4	V
	I _{OL} = 24 mA		3 V		0.55	
I _I	V _I = 5.5 V or GND		3.6 V		±5	μA
I _{CC}	V _I = V _{CC} or GND	I _O = 0	3.6 V		10	μA

over operating free-air temperature range (unless otherwise noted)

		V _{cc}	SN54LVC86A	
PARAMETER	PARAMETER TEST CONDITIONS		–55 TO 125°C	UNIT
			MIN TYP MAX	
ΔI _{CC}	One input at V_{CC} – 0.6 V, Other inputs at V_{CC} or GND	2.7 V to 3.6 V	500	μА
C _i	$V_I = V_{CC}$ or GND	3.3 V	5 ⁽¹⁾	pF

(1) $T_A = 25^{\circ}C$

5.7 Electrical Characteristics, SN74LVC86A

over operating free-air temperature range (unless otherwise noted)

	·			,		;	SN74LVC86A	١			
PARAMETER	TEST CONDITION	IS	V _{cc}	T _A = 25°C			-40 TO 85°C		-40 TO 125°C		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
	$I_{OH} = -100 \mu A$		1.65V to 3.6V	V _{CC} - 0.2			V _{CC} - 0.2		V _{CC} - 0.3		
	$I_{OH} = -4mA$		1.65V	1.29			1.2		1.05		
V	I _{OH} = -8mA		2.3V	1.9			1.7		1.55		v
V _{OH}	I _{OH} = -12mA		2.7V	2.2			2.2		2.05		v
	1 _{OH} = -12MA		3V	2.4			2.4		2.25		
	I _{OH} = -24mA		3V	2.3			2.2		2		
	I _{OL} = 100μA		1.65V to 3.6V			0.1		0.2		0.3	
	I _{OL} = 4mA		1.65V			0.24		0.45		0.6	
V _{OL}	I _{OL} = 8mA		2.3V			0.3		0.7		0.75	V
	I _{OL} = 12mA		2.7V			0.4		0.4		0.6	
	I _{OL} = 24mA		3V			0.55		0.55		0.8	
I _I	V _I = 5.5V or GND		3.6V			±1		±5		±20	μA
Icc	V _I = V _{CC} or GND	I _O = 0	3.6V			1		10		40	μΑ
ΔI _{CC}	One input at V _{CC} – 0.6V Other inputs at V _{CC} or 0		2.7V to 3.6V			500		500		5000	μA
C _i	V _I = V _{CC} or GND		3.3V		5						pF

5.8 Switching Characteristics, SN54LVC86A

over recommended operating free-air temperature range (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{cc}	SN54LV -55 TO		UNIT
	(5.)	(33.1.3.1)		MIN	MAX	
t _{pd} A	V	2.7 V		5.6		
	A	T	3.3 V ± 0.3 V	1	4.6	ns

5.9 Switching Characteristics, SN74LVC86A

over recommended operating free-air temperature range (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

						SN	74LVC86	Α			
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC}	TA	= 25°C		-40 TO	85°C	-40 TO	125°C	UNIT
	((001101)		MIN	TYP	MAX	MIN	MAX	MIN	MAX	
			1.8V ± 0.15V	1	4.1	9.4	1	9.9	1	11.4	
+ .	Α	Y	2.5V ± 0.2V	1	2.9	7.1	1	7.6	1	9.7	ns
^L pd	A	'	2.7V	1	2.8	5.4	1	5.6	1	7.1	115
			3.3V ± 0.3V	1	2.5	4.4	1	4.6	1	5.8	

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over recommended operating free-air temperature range (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

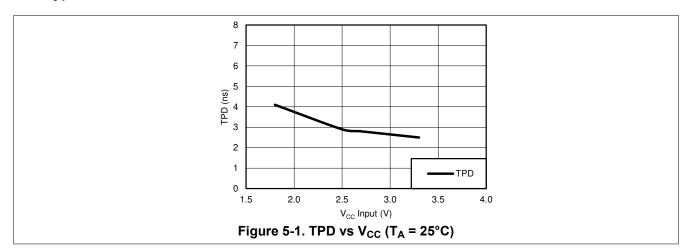
		то				SN	74LVC86	A			
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC}	TA	= 25°C		-40 TO	85°C	-40 TO	125°C	UNIT
	((001101)		MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t _{sk(o)}			3.3V ± 0.3V					1		1.5	ns

5.10 Operating Characteristics

 $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	V _{cc}	TYP	UNIT
			1.8V	6.5	
С	Power dissipation capacitance per gate	f = 10 MHz	2.5V	7.5	pF
			3.3V	8.5	

5.11 Typical Characteristics



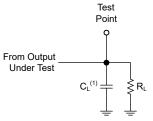


6 Parameter Measurement Information

Phase relationships between waveforms were chosen arbitrarily for the examples listed in the following table. All input pulses are supplied by generators having the following characteristics: PRR \leq 1MHz, $Z_O = 50\Omega$, $t_t \leq$ 2.5ns.

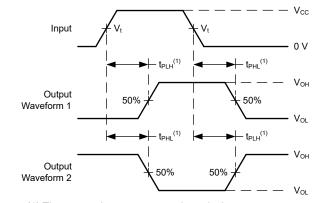
The outputs are measured individually with one input transition per measurement.

V _{cc}	V _t	R _L	CL	ΔV
1.8V ± 0.15V	V _{CC} /2	1kΩ	30pF	0.15V
2.5V ± 0.2V	V _{CC} /2	500Ω	30pF	0.15V
2.7V	1.5V	500Ω	50pF	0.3V
3.3V ± 0.3V	1.5V	500Ω	50pF	0.3V



(1) C_L includes probe and test-fixture capacitance.

Figure 6-1. Load Circuit for Push-Pull Outputs



(1) The greater between t_{PLH} and t_{PHL} is the same as t_{pd} . Figure 6-2. Voltage Waveforms Propagation Delays

Input $\frac{10\%}{10\%} - \frac{10\%}{10\%} = 0 \text{ V}_{\text{CC}}$ Output $\frac{10\%}{10\%} - \frac{10\%}{10\%} = 0 \text{ V}_{\text{OH}}$

(1) The greater between t_r and t_f is the same as t_t .

Figure 6-3. Voltage Waveforms, Input and Output Transition Times

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7 Detailed Description

7.1 Overview

The 'LVC86A devices perform the Boolean function Y = A \oplus B or Y = $\overline{A}B + A \overline{B}$ in positive logic.

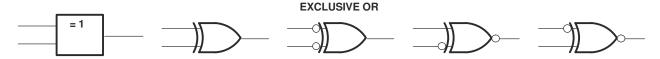
A common application is as a true/complement element. If one of the inputs is low, the other input is reproduced in true form at the output. If one of the inputs is high, the signal on the other input is reproduced inverted at the output.

Inputs can be driven from either 3.3V or 5V devices. This feature allows the use of these devices as down-translators in a mixed 3.3V/5V system environment.

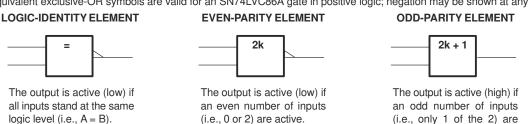
7.2 Functional Block Diagram

Exclusive-OR Logic

An exclusive-OR gate has many applications, some of which can be represented better by alternative logic symbols.



These five equivalent exclusive-OR symbols are valid for an SN74LVC86A gate in positive logic; negation may be shown at any two ports.



active.

7.3 Feature Description

- Wide operating voltage range
 - Operates from 1.65 V to 3.6 V
- Allows up or down voltage translation
 - Inputs and outputs accept voltages to 5.5 V

7.4 Device Functional Modes

Table 7-1. FUNCTION TABLE (EACH GATE)

INP	UTS	OUTPUT
Α	В	Υ
L	L	L
L	Н	Н
Н	L	Н
Н	Н	L

8 Application and Implementation

8.1 Application Information

The SN74LVC86A device is a high-drive, open-drain CMOS device that can be used for a multitude of buffer-type functions. It can produce 24 mA of drive current at 3 V. Therefore, this device is ideal for driving multiple inputs and for high-speed applications up to 100 MHz. The inputs and outputs are 5.5-V tolerant allowing the device to translate up to 5.5 V or down to V_{CC} .

8.2 Typical Application

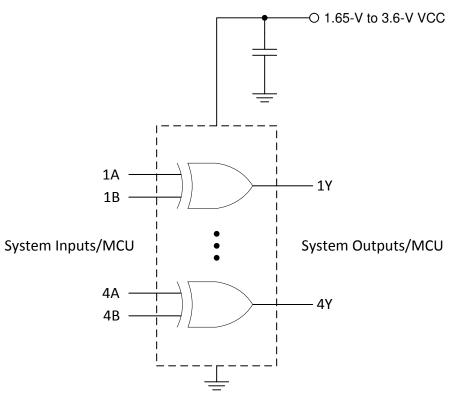


Figure 8-1. Typical OR Gate Application and Supply Voltage

8.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads; therefore, routing and load conditions should be considered to prevent ringing.

8.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions
 - Rise time and fall time specs: See (Δt/ΔV) in the Section 5.3 table.
 - Specified high and low levels: See (V_{IH} and V_{IL}) in the Section 5.3 table.
 - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid V_{CC}.
- 2. Recommend Output Conditions
 - Load currents should not exceed 25 mA per output and 50 mA total for the part.
 - Outputs should not be pulled above 5.5 V.



8.2.3 Application Curves

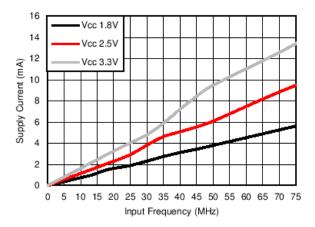


Figure 8-2. Supply Current vs. Input Frequency

Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the Section 5.3 table.

Each V_{CC} pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1 μ F is recommended; if there are multiple V_{CC} pins, then 0.01 μ F or 0.022 μ F is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1 μ F and a 1 μ F are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

8.3 Layout

8.3.1 Layout Guidelines

When using multiple bit logic devices inputs should never float.

In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Section 8.3.2 specifies the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} , whichever makes more sense or is more convenient. It is generally acceptable to float outputs, unless the part is a transceiver.



8.3.2 Layout Example

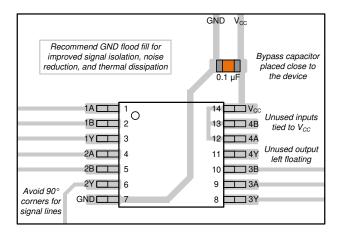


Figure 8-3. Example Layout for the SN74LVC86A



9 Device and Documentation Support

9.1 Documentation Support (Analog)

9.1.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 9-1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN54LVC86A	Click here	Click here	Click here	Click here	Click here
SN74LVC86A	Click here	Click here	Click here	Click here	Click here

9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

9.4 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision Q (May 2024) to Revision R (August 2024)

Page

Changes from Revision P (April 2005) to Revision Q (April 2024)

Page

- Added Device Information table, Pin Functions table, ESD Ratings table, Thermal Information table, Device Functional Modes, Application and Implementation section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section
- Deleted references to machine model1



11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: SN54LVC86A SN74LVC86A





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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9761901Q2A	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9761901Q2A SNJ54LVC 86AFK	Samples
5962-9761901QDA	ACTIVE	CFP	W	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9761901QD A SNJ54LVC86AW	Samples
SN74LVC86ABQAR	ACTIVE	WQFN	BQA	14	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC86A	Samples
SN74LVC86AD	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC86A	Samples
SN74LVC86ADBR	ACTIVE	SSOP	DB	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC86A	Samples
SN74LVC86ADG4	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC86A	Samples
SN74LVC86ADR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC86A	Samples
SN74LVC86ADRG4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC86A	Samples
SN74LVC86ADT	ACTIVE	SOIC	D	14	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC86A	Samples
SN74LVC86ANSR	ACTIVE	SOP	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC86A	Samples
SN74LVC86APW	ACTIVE	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC86A	Samples
SN74LVC86APWE4	ACTIVE	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC86A	Samples
SN74LVC86APWG4	ACTIVE	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC86A	Samples
SN74LVC86APWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC86A	Samples
SN74LVC86APWRG4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC86A	Samples
SN74LVC86ARGYR	ACTIVE	VQFN	RGY	14	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	LC86A	Samples
SN74LVC86ARGYRG4	ACTIVE	VQFN	RGY	14	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	LC86A	Samples
SNJ54LVC86AFK	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9761901Q2A	Samples

PACKAGE OPTION ADDENDUM

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Orderable Device	Status (1)	Package Type	Package Drawing		Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							V-7			SNJ54LVC 86AFK	
SNJ54LVC86AW	ACTIVE	CFP	W	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9761901QD A SNJ54LVC86AW	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

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OTHER QUALIFIED VERSIONS OF SN54LVC86A, SN74LVC86A:

Catalog: SN74LVC86A

• Automotive : SN74LVC86A-Q1, SN74LVC86A-Q1

• Enhanced Product : SN74LVC86A-EP, SN74LVC86A-EP

Military: SN54LVC86A

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

• Enhanced Product - Supports Defense, Aerospace and Medical Applications

• Military - QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION

NSTRUMENTS





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC86ABQAR	WQFN	BQA	14	3000	180.0	12.4	2.8	3.3	1.1	4.0	12.0	Q1
SN74LVC86ADBR	SSOP	DB	14	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN74LVC86ADR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LVC86ADT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LVC86ANSR	SOP	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN74LVC86APWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC86ARGYR	VQFN	RGY	14	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1



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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC86ABQAR	WQFN	BQA	14	3000	210.0	185.0	35.0
SN74LVC86ADBR	SSOP	DB	14	2000	356.0	356.0	35.0
SN74LVC86ADR	SOIC	D	14	2500	356.0	356.0	35.0
SN74LVC86ADT	SOIC	D	14	250	210.0	185.0	35.0
SN74LVC86ANSR	SOP	NS	14	2000	356.0	356.0	35.0
SN74LVC86APWR	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74LVC86ARGYR	VQFN	RGY	14	3000	356.0	356.0	35.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
5962-9761901Q2A	FK	LCCC	20	55	506.98	12.06	2030	NA
SN74LVC86AD	D	SOIC	14	50	506.6	8	3940	4.32
SN74LVC86ADG4	D	SOIC	14	50	506.6	8	3940	4.32
SN74LVC86APW	PW	TSSOP	14	90	530	10.2	3600	3.5
SN74LVC86APWE4	PW	TSSOP	14	90	530	10.2	3600	3.5
SN74LVC86APWG4	PW	TSSOP	14	90	530	10.2	3600	3.5
SNJ54LVC86AFK	FK	LCCC	20	55	506.98	12.06	2030	NA



SMALL OUTLINE INTEGRATED CIRCUIT



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
- 5. Reference JEDEC registration MS-012, variation AB.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- G. Package complies to JEDEC MO-241 variation BA.



RGY (S-PVQFN-N14)

PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No—Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

4206353-2/P 03/14

NOTE: All linear dimensions are in millimeters



RGY (S-PVQFN-N14)

PLASTIC QUAD FLATPACK NO-LEAD



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



2.5 x 3, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



INSTRUMENTS www.ti.com

PLASTIC QUAD FLAT PACK-NO LEAD



- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.



PLASTIC QUAD FLAT PACK-NO LEAD



NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC QUAD FLAT PACK-NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



W (R-GDFP-F14)

CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within MIL STD 1835 GDFP1-F14







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-150.





NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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